

Voltage Tracker

250 mA Output Voltage Tracker

BD42530xxx-C Series

General Description

The BD42530xxx-C Series are voltage trackers featuring 45 V absolute maximum voltage, output voltage tracking accuracy of ± 10 mV, 250 mA output current and 40 μ A (Typ) low current consumption.

These trackers are therefore ideal for applications requiring a direct connection to the battery and a low current consumption.

Ceramic capacitors can be used for phase compensation capacitor of the output. Furthermore, these ICs also feature overcurrent protection to protect the device from damage caused by short-circuiting and an integrated thermal shutdown to protect the device from overheating at overload conditions.

Packages

- W (Typ) x D (Typ) x H (Max)
- EFJ : HTSOP-J8
- 4.90 mm x 6.00 mm x 1.00 mm



■ FP2 : TO263-5

10.16 mm x 15.10 mm x 4.70 mm

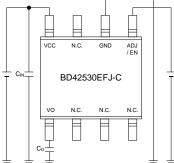


Applications

 Automotive (Engine-ECU, Body, Air-Conditioner etc.)

Typical Application Circuits

■ Components externally connected: 1 µF ≤ C_{IN} (Min), 4.7 µF ≤ C_O (Min) Ceramic capacitors with less change in ESR due to tem<u>perature</u> characteristics are recommended.



OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

Features

- AEC-Q100 Qualified ^(Note 1)
 Qualified for Automotive Applications
 Wide Temperature Range (Tj): -40 °C to +150 °C
 Wide Operating Input Range: 3 V to 42 V
 Low Quiescent Current: 40 µA (Typ)
 Output Voltage Tracking Accuracy: ±10 mV
 Over Current Protection (OCP)
 Thermal Shutdown Protection (TSD) (Note 1: Grade 1)
- FPJ : TO252-J5
- 6.60 mm x 10.10 mm x 2.38 mm



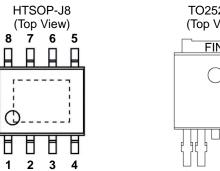
Ordering Information

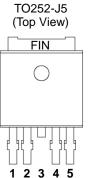
| В | D | 4 | 2 | 5 | 3 | 0 | Е | F | J |] — | С | E2 |
|---------|------|---|---|------------|--------------------------------------|------|------------|---------|----------------|----------------------|-----------------------|-------------------------|
| Part Nu | mber | | | EFJ FPJ | kage : HTSO : TO252 : TO263 | 2-J5 | C: for Aut | omotive | Packa E2: E | aging and mbossed | I Forming Tape and | Specification d Reel |

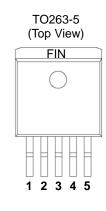
Lineup

| Output Current | Pack | kage | Orderable Part Number |
|----------------|----------|--------------|-----------------------|
| | HTSOP-J8 | Reel of 2500 | BD42530EFJ-CE2 |
| 250 mA | TO252-J5 | Reel of 2000 | BD42530FPJ-CE2 |
| | TO263-5 | Reel of 500 | BD42530FP2-CE2 |

Pin Configurations







Pin Descriptions

HTSOP-J8 (Note 1), (Note 2), (Note 3)

| Pin No. | Pin Name | Function |
|---------|----------|------------------------|
| 1 | VO | Output |
| 2 | N.C. | Not connected |
| 3 | N.C. | Not connected |
| 4 | N.C. | Not connected |
| 5 | ADJ / EN | Output Control Voltage |
| 6 | GND | Ground |
| 7 | N.C. | Not connected |
| 8 | VCC | Input |
| | | |

Note 1: N.C. Pin is recommended to short with GND. Note 2: N.C. Pin can be open because it isn't connect it inside of IC.

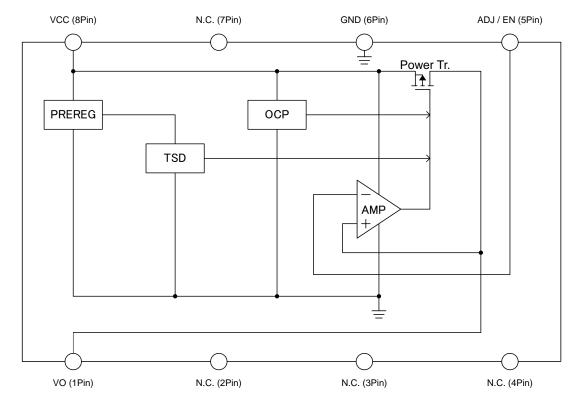
Note 2: Reposed die pad is connected to GND in the inside of IC. Exposed die pad is need to be connected to GND of the board.

TO252-J5^(Note 1) (Note 2) / TO263-5 (Note 1) (Note 2)

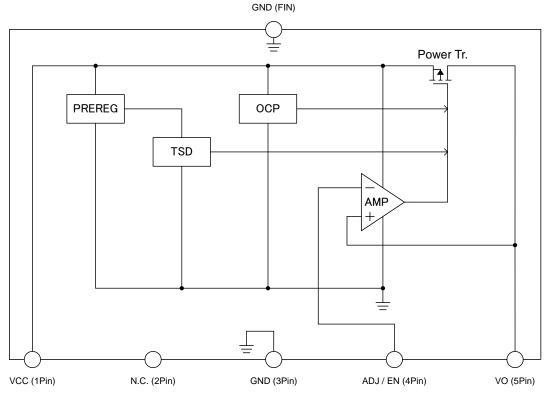
| Pin No. | Pin Name | Function | | |
|---------|----------|------------------------|--|--|
| 1 | VCC | Input | | |
| 2 | N.C. | Not connected | | |
| 3 | GND | Ground | | |
| 4 | ADJ / EN | Output Control Voltage | | |
| 5 | VO | Output | | |
| FIN GND | | Ground | | |

Block Diagrams

HTSOP-J8



TO252-J5 / TO263-5



Description of Blocks

| Block Name | Function | Description of Blocks | | |
|-----------------------------------|--|---|--|--|
| PREREG | Internal Power Supply | Power Supply for Internal Circuit | | |
| TSD | Thermal Shutdown Protection | The TSD protect the device from overheating. If the chip temperature (Tj) reaches ca. 175 °C (Typ), the output is turned off. | | |
| OCP | Over Current Protection | The OCP protect the device from damage caused by ove current. (Typ:650mA at 25°C) | | |
| AMP | Amplifier for the Power Transistor Drive | The amplifier drives output power transistor with ADJ/EN voltage as reference voltage. | | |
| Power Tr. Output Power Transistor | | PDMOS type output power transistor. | | |

Absolute Maximum Ratings

| Paramet | er | Symbol | Ratings | Unit | |
|------------------------------|----------|----------|-------------------------------|-------------|----|
| Supply Voltage | (Note 1) | Vcc | -0.3 to +45 | V | |
| Output Control Voltage | | | | -0.3 to +28 | V |
| Output Voltage | | | Vo | -0.3 to +28 | V |
| Junction Temperature Range | | Tj | -40 to +150 | °C | |
| Storage Temperature Range | | | Tstg | -55 to +150 | °C |
| Maximum Junction Temperature | | | Tjmax | +150 | °C |
| FCD with story d \/sltage | НВМ | (Note 2) | $V_{\text{ESD}, \text{ HBM}}$ | ±2000 | V |
| ESD withstand Voltage | CDM | (Note 3) | $V_{\text{ESD, CDM}}$ | ±1000 | V |

(Note 1) Do not exceed Junction Temperature.

(Note 2) Human Body Model.

(Note 3) Charged Device Model.

(Caution) Exceeding the absolute maximum rating for supply voltage, operating temperature or other parameters can result in damages to or destruction of the chip. In this event it also becomes impossible to determine the cause of the damage (e.g. short circuit, open circuit, etc.). Therefore, if any special mode is being considered with values expected to exceed the absolute maximum ratings, implementing physical safety measures, such as adding fuses, should be considered.

Operating Range (-40 °C ≤ Tj ≤ +150 °C)

| Parameter | Symbol | Min | Max | Unit |
|---------------------------|-----------------------|-----|-----|------|
| Supply Voltage (Note 1) | V _{CC} | 5.6 | 42 | V |
| Tracking Voltage (Note 2) | V _{ADJ / EN} | 2 | 16 | V |
| Start-Up Voltage (Note 3) | V _{CC} | 3 | - | V |
| Output Current | lo | 0 | 250 | mA |
| Ambient Temperature Range | Та | -40 | 125 | °C |

(Note 1) $V_{ADJ/EN} = 5V, I_O = 200mA$

(Note 2) $V_{ADJ/EN} \leq Vcc - 0.5V$

(Note 3) $I_0 = 0 \text{ mA}.$

Operating Conditions

| Parameter | Symbol | | | Unit | Condition | | |
|------------------|--------|-------------------------|-----|------|-----------|---------------------------------------|--|
| Falametei | Symbol | Min | Тур | Max | Onit | Condition | |
| Input Capacitor | CIN | 1 ^(Note 4) | - | - | μF | Ceramic capacitor | |
| Output Capacitor | Co | 4.7 ^(Note 4) | - | - | μF | Ceramic capacitor ^(Note 5) | |

The minimum value of capacitor must be met this specifications over full operating conditions. (Note 4)

(ex. Temperature, DC bias)

Electrolytic capacitor and tantalum capacitor can be used satisfying ESR of the stable operation range of the "output capacitor ESR vs. output current" of Figure 17. (Note 5)

Thermal Resistance(Note 1)

| Deremeter | Symbol | Thermal Res | 1.1 | |
|--|-----------------|------------------------|--------------------------|------|
| Parameter | Symbol | 1s ^(Note 3) | 2s2p ^(Note 4) | Unit |
| HTSOP-J8 | | | | |
| Junction to Ambient | θ _{JA} | 130 | 34 | °C/W |
| Junction to Top Characterization Parameter ^(Note 2) | Ψ_{JT} | 15 | 7 | °C/W |
| TO252-J5 | | | | |
| Junction to Ambient | θ _{JA} | 136 | 23 | °C/W |
| Junction to Top Characterization Parameter ^(Note 2) | Ψ_{JT} | 17 | 3 | °C/W |
| TO263-5 | | | | |
| Junction to Ambient | θ _{JA} | 81 | 21 | °C/W |
| Junction to Top Characterization Parameter ^(Note 2) | Ψ_{JT} | 8 | 2 | °C/W |

(Note 1)Based on JESD51-2A(Still-Air)
 (Note 2)The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.
 (Note 3)Using a PCB board based on JESD51-3.

| Layer Number of Measurement Board | Material | Board Size | | | | | |
|--------------------------------------|-----------|----------------------------|--|--|--|--|--|
| Single | FR-4 | 114.3mm x 76.2mm x 1.57mmt | | | | | |
| Тор | | | | | | | |
| Copper Pattern | Thickness | | | | | | |
| Footprints and Traces | 70µm | | | | | | |

(Note 4)Using a PCB board based on JESD51-7.

| Layer Number of | Material | Board Size | | Thermal V | ia ^(Note 5) | |
|-----------------------|-----------|--------------------|-----------|----------------|------------------------|--|
| Measurement Board | Material | Board Size | | Pitch | Diameter | |
| 4 Layers | FR-4 | 114.3mm x 76.2mm x | x 1.6mmt | 1.20mm | Ф0.30mm | |
| Тор | | 2 Internal Laye | ers | Bottom | | |
| Copper Pattern | Thickness | Copper Pattern | Thickness | Copper Pattern | Thickness | |
| Footprints and Traces | 70µm | 74.2mm x 74.2mm | 35µm | 74.2mm x 74.2m | m 70µm | |

(Note 5) This thermal via connects with the copper pattern of all layers.

Electrical Characteristics

(Unless otherwise specified, -40 °C \leq Tj \leq +150 °C, V_{CC} = 13.5 V, V_{ADJ/EN} = 5 V, I_O = 0 mA. The Typical value is defined at Tj = 25 °C.)

| Parameter | Symbol | | | | Unit | Conditions | |
|----------------------------------|--------|-----|------|------|------|--|--|
| Falameter | Symbol | Min | Тур | Max | Unit | Conditions | |
| Circuit Current | Icc | - | 40 | 80 | μA | lo ≤ 250 mA | |
| | | -10 | - | 10 | mV | $3.5V \le Vcc \le 32V$ $0.1 \text{ mA} \le I_0 \le 100 \text{ mA}$ $V_{ADJ/EN} = 2V$ | |
| Output Voltage Tracking Accuracy | ΔVo | -10 | - | 10 | mV | $3.8V \le Vcc \le 32V$ $0.1 \text{ mA} \le I_0 \le 250 \text{ mA}$ $V_{ADJ/EN} = 2V$ | |
| | | -10 | - | 10 | mV | $6V \le Vcc \le 32V$ $0.1 \text{ mA} \le I_O \le 250 \text{ mA}$ $V_{ADJ/EN} = 5V$ | |
| Dropout Voltage | ΔVd | - | 0.28 | 0.60 | V | $V_{CC} = V_O \times 0.95 (= 4.75 \text{ V: Typ})$ $I_O = 200 \text{ mA}$ | |
| Ripple Rejection | R.R. | - | 80 | - | dB | f = 120 Hz, ein = 1 Vrms $I_0 = 100$ mA | |
| Thermal Shut Down | TSD | - | 175 | - | °C | Tj at TSD ON | |

Electrical Characteristics (Output Control Function)

<u>(Unless otherwise specified, -40 °C ≤ Tj ≤ +150 °C, V_{CC} = 13.5 V, Io = 0 mA. The Typical value is defined at Tj = 25 °C.</u>)

| Parameter | Symbol | Limit | | | Unit | Conditions |
|---------------------------|-----------------------|-------|-----|-----|------|--|
| | | Min | Тур | Max | Onit | Conditions |
| Shutdown Current | Ishut | - | 1 | 5 | μA | V _{ADJ / EN} ≤ 0.4 V Tj ≤ 125 °C |
| ADJ / EN ON Mode Voltage | VthH | 2 | - | 16 | V | Active Mode |
| ADJ / EN OFF Mode Voltage | VthL | 0 | - | 0.4 | V | Off Mode |
| ADJ / EN Bias Current | I _{ADJ / EN} | - | 1 | 3 | μA | V _{ADJ/EN} =5 V |

Typical Performance Curves

Unless otherwise specified: -40 °C \leq Tj \leq +150 °C, V_{CC} = 13.5 V, V_{ADJ/EN} = 5 V, Io = 0 mA.

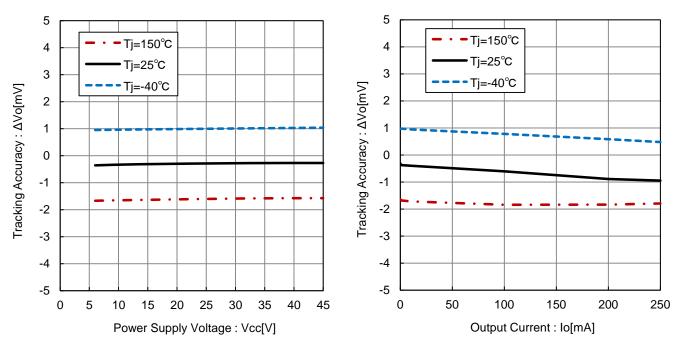
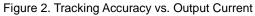


Figure 1. Tracking Accuracy vs. Power Supply Voltage



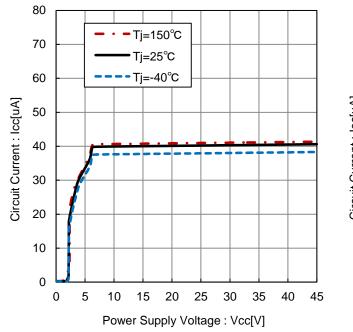


Figure 3. Circuit Current vs. Power Supply Voltage

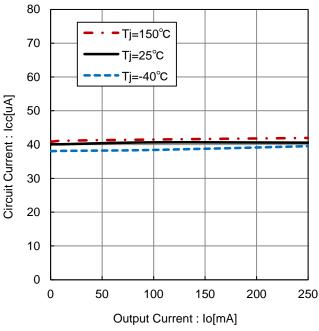


Figure 4. Circuit Current vs. Output Current

Typical Performance Curves – continued

Unless otherwise specified: -40 °C ≤ Tj ≤ +150 °C, V_{CC} = 13.5 V, $V_{ADJ/EN}$ = 5 V, Io = 0 mA.

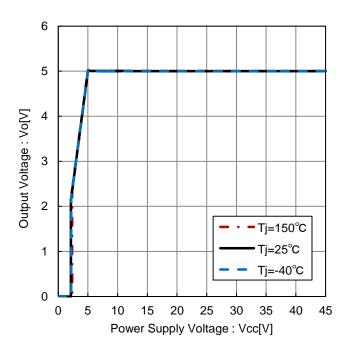


Figure 5. Output Voltage vs. Power Supply Voltage

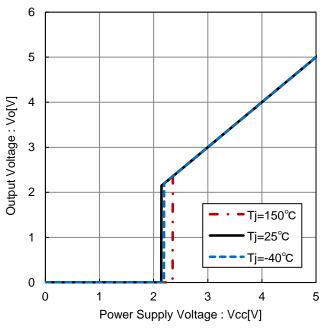
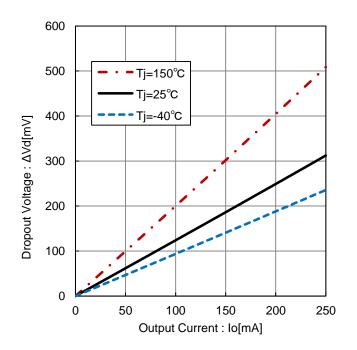
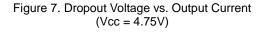


Figure 6. Output Voltage vs. Power Supply Voltage at Low Supply Voltage





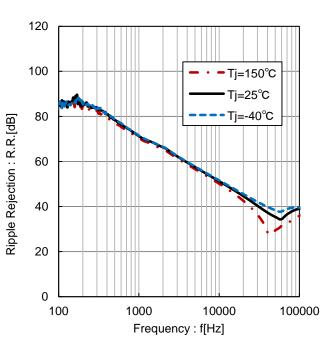
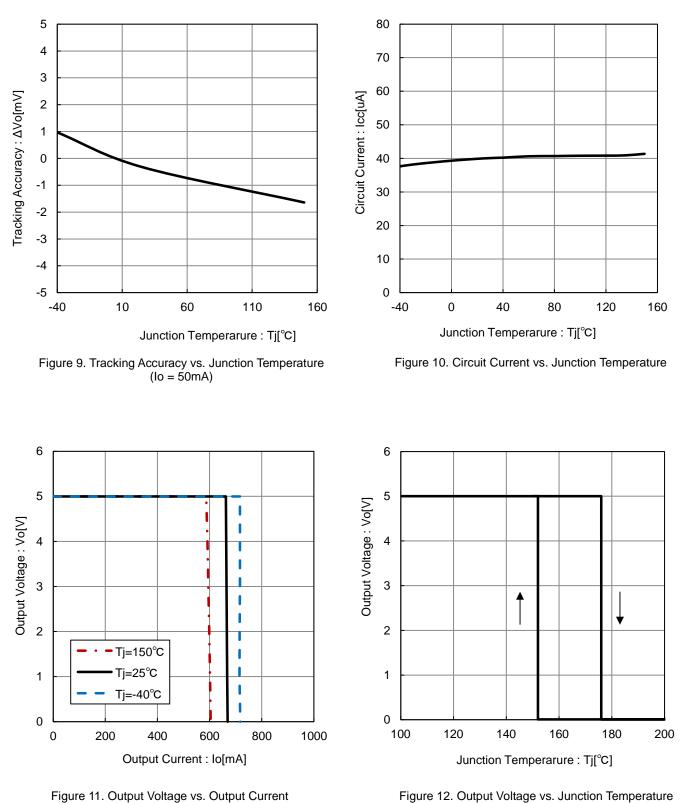
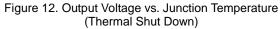


Figure 8. Ripple Rejection vs. Frequency (ein = 1Vrms, Io = 100mA)

Typical Performance Curves – continued

Unless otherwise specified: -40 °C ≤ Tj ≤ +150 °C, V_{CC} = 13.5 V, $V_{ADJ/EN}$ = 5 V, Io = 0 mA.





(Over Current Protection)

Typical Performance Curves – continued

Unless otherwise specified: -40 °C ≤ Tj ≤ +150 °C, V_{CC} = 13.5 V, $V_{ADJ/EN}$ = 5 V, Io = 0 mA.

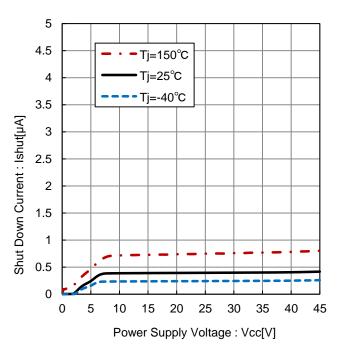


Figure 13. Shut Down Current vs. Power Supply Voltage

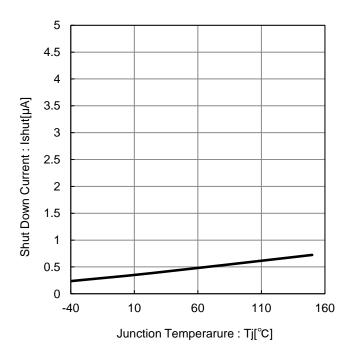
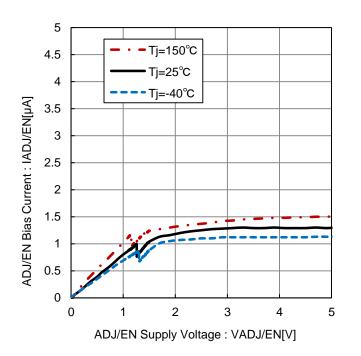
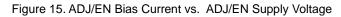


Figure 14. Shut Down Current vs. Junction Temperature





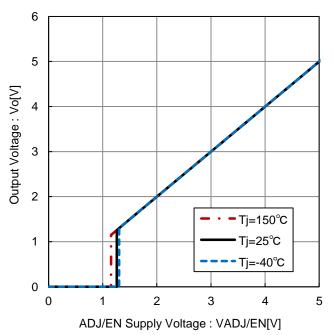
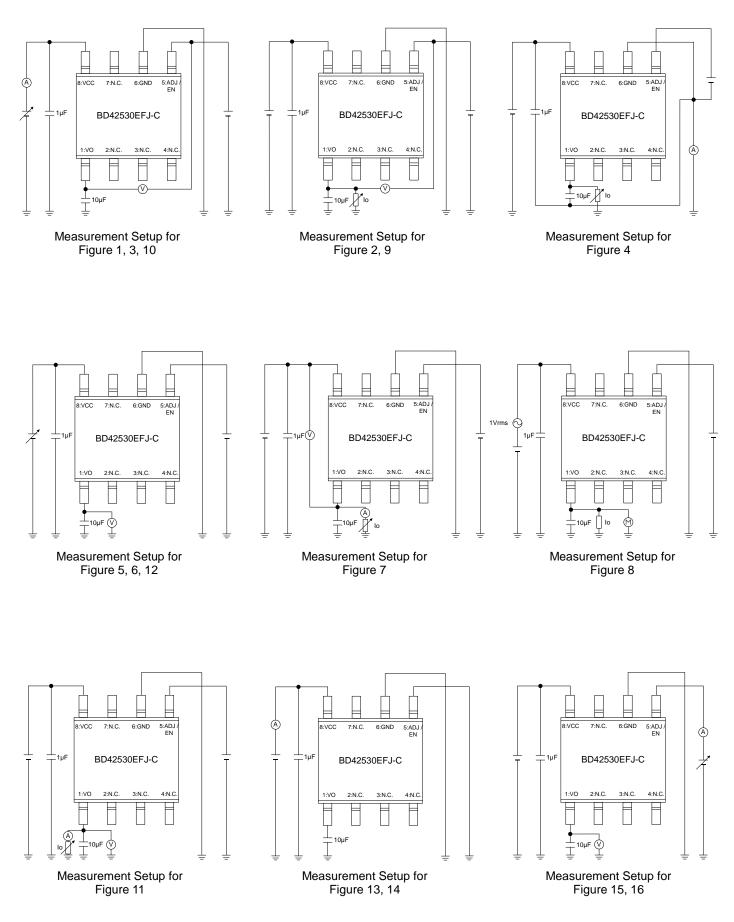


Figure 16. Output Voltage vs. ADJ/EN Supply Voltage

Measurement Circuit



Selection of Components Externally Connected

VCC Pin

Insert Capacitors with a capacitance of 1 μ F (Min) or higher between the VCC and GND. Choose the capacitance according to the line between the power smoothing circuit and the VCC. Selection of the capacitance also depends on the application. Verify the application and allow sufficient margins in the design. We recommend to mount the capacitor as close as possible to the pin. When selecting the capacitor, ensure that the capacitance of 1 μ F or higher is maintained at the intended applied voltage and temperature range.

Output Pin Capacitor

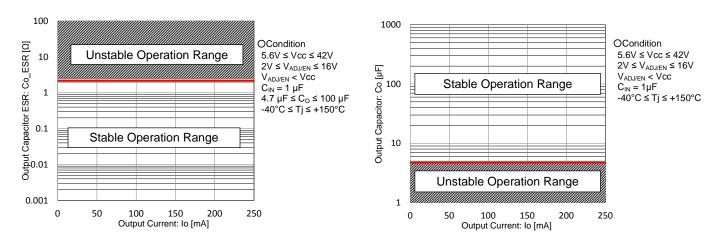
In order to prevent oscillation, a capacitor needs to be placed between the output pin and GND. We recommend using a capacitor with a capacitance of 4.7 μ F (Min) or higher. Ceramic, Electrolytic and tantalum capacitors can be used. When selecting the capacitor, ensure that the capacitance of 4.7 μ F or higher is maintained at the intended applied voltage and temperature range. Capacitance fluctuation due to changes in temperature can possibly result in oscillation. For selection of the capacitor refer to the data of Figure 18.

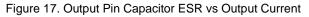
The stable operation range given in the data of Figure 17 is based on the standalone IC and resistive load. For actual applications the stable operating range is influenced by the PCB impedance, input supply impedance and load impedance. Therefore verification of the final operating environment is needed.

When selecting a ceramic type capacitor, we recommend using X5R, X7R or better with excellent temperature and DC-biasing characteristics and high voltage tolerance.

When the above-mentioned Output Pin Capacitor and the bypass capacitor for the rear stage may be connected in parallel, oscillation may occur due to the deterioration of phase characteristic depending on the ESR value of the Output Pin Capacitor. In such case, select ceramic capacitor of 4.7μ F or more as the bypass capacitor. Or insert additional ceramic capacitor of 4.7μ F or more.

Also, in case of rapidly changing input voltage and load current, select the capacitance in accordance with verifying that the actual application meets with the required specification. Mount the capacitor as close as possible to the connected pin.







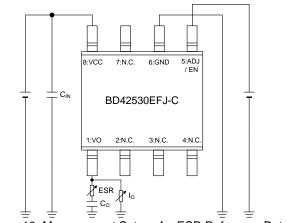
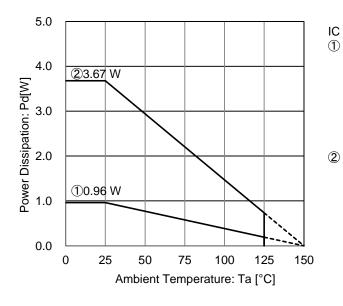
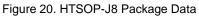


Figure 19. Measurement Setups for ESR Reference Data

Power Dissipation

∎HTSOP-J8





∎TO252-J5

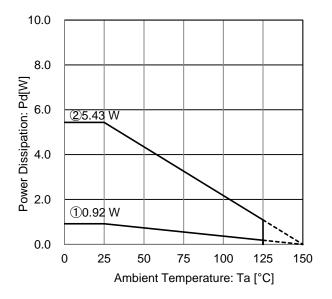


Figure 21. TO252-J5 Package Data

IC mounted on ROHM standard board based on JEDEC. (1) : 1 - layer PCB (Copper foil area on the reverse side of PCB: 0 mm x 0 mm) Board material: FR4 Board size: 114.3 mm x 76.2 mm x 1.57 mmt Mount condition: PCB and exposed pad are soldered. Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.

: 4 - layer PCB
(2 inner layers and Copper foil area on the reverse side of PCB: 74.2 mm x 74.2 mm)
Board material: FR4
Board size: 114.3 mm x 76.2 mm x 1.60 mmt
Mount condition: PCB and exposed pad are soldered.
Top copper foil: ROHM recommended
footprint + wiring to measure, 2 oz. copper.
2 inner layers copper foil area of PCB
: 74.2 mm x 74.2 mm, 1 oz. copper.
Copper foil area on the reverse side of PCB
: 74.2 mm x 74.2 mm, 2 oz. copper.

Condition(1): θ_{JA} = 130 °C / W, Ψ_{JT} (top center) = 15 °C / W Condition(2): θ_{JA} = 34 °C / W, Ψ_{JT} (top center) = 7 °C / W

IC mounted on ROHM standard board based on JEDEC.

 : 1 - layer PCB (Copper foil area on the reverse side of PCB: 0 mm x 0 mm) Board material: FR4 Board size: 114.3 mm x 76.2 mm x 1.57 mmt Mount condition: PCB and exposed pad are soldered. Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.

: 4 - layer PCB
(2 inner layers and Copper foil area on the reverse side of PCB: 74.2 mm x 74.2 mm)
Board material: FR4
Board size: 114.3 mm x 76.2 mm x 1.60 mmt
Mount condition: PCB and exposed pad are soldered.
Top copper foil: ROHM recommended
footprint + wiring to measure, 2 oz. copper.
2 inner layers copper foil area of PCB
: 74.2 mm x 74.2 mm, 1 oz. copper.
Copper foil area on the reverse side of PCB
: 74.2 mm x 74.2 mm, 2 oz. copper.

Condition(1): $\theta_{JA} = 136 \text{ °C} / W$, Ψ_{JT} (top center) = 17 °C / W Condition(2): $\theta_{JA} = 23 \text{ °C} / W$, Ψ_{JT} (top center) = 3 °C / W



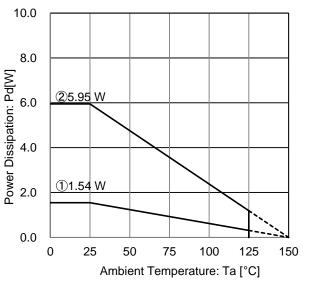


Figure 22. TO263-5 Package Data

IC mounted on ROHM standard board based on JEDEC. (1): 1 - layer PCB (Copper foil area on the reverse side of PCB: 0 mm x 0 mm) Board material: FR4 Board size: 114.3 mm x 76.2 mm x 1.57 mm Mount condition: PCB and exposed pad are soldered. Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper. 2 : 4 - layer PCB (2 inner layers and Copper foil area on the reverse side of PCB: 74.2 mm x 74.2 mm) Board material: FR4 Board size: 114.3 mm x 76.2 mm x 1.60 mm Mount condition: PCB and exposed pad are soldered. Top copper foil: ROHM recommended

footprint + wiring to measure, 2 oz. copper. 2 inner layers copper foil area of PCB : 74.2 mm x 74.2 mm, 1 oz. copper.

Copper foil area on the reverse side of PCB : 74.2 mm x 74.2 mm, 2 oz. copper.

Thermal Design

Within this product, the power consumption is decided by the dropout voltage condition, the load current and the circuit current. Refer to Package Data illustrated in Figure 20, 21, 22 when using the IC in an environment of Ta \geq 25 °C. Even if the ambient temperature Ta is at 25 °C, depending on the input voltage and the load current, chip junction temperature can be very high. Consider the design to be Tj \leq Tjmax = 150 °C in all possible operating temperature range. On the reverse side of the package (HTSOP-J8, TO252-J5, TO263-5) there is exposed heat pad for improving the heat dissipation.

Should by any condition the maximum junction temperature Tjmax = 150 °C rating be exceeded by the temperature increase of the chip, it may result in deterioration of the properties of the chip. The thermal impedance in this specification is based on recommended PCB and measurement condition by JEDEC standard. Verify the application and allow sufficient margins in the thermal design by the following method is used to calculate the junction temperature Tj. Tj can be calculated by either of the two following methods.

1. The following method is used to calculate the junction temperature Tj.

$$Tj = Ta + P_C \times \theta_{A}$$

Where:

| Tj | : Junction Temperature |
|-------------------|--|
| Та | : Ambient Temperature |
| $P_{\mathcal{C}}$ | : Power Consumption |
| $	heta_{JA}$ | : Thermal Impedance (Junction to Ambient) |
| | |

2. The following method is also used to calculate the junction temperature Tj.

$$Tj = T_T + P_C \times \Psi_{JT}$$

Where

| : Junction Temperature |
|---|
| : Top Center of Case's (mold) Temperature |
| : Power consumption |
| : Thermal Impedance |
| (Junction to Top Center of Case) |
| |

The following method is used to calculate the power consumption Pc (W).

$$Pc = (V_{CC} - V_0) \times I_0 + V_{CC} \times I_{CC}$$

Where:

| PC | : Power Consumption : Input Voltage | | |
|-----------------|--|--|--|
| V _{CC} | | | |
| Vo | : Output Voltage | | |
| Io | : Load Current | | |
| ICC | : Circuit Current | | |

- Calculation Example (HTSOP-J8)

If V_{CC} = 13.5 V, V_O = 5.0 V, I_O = 50 mA, I_{CC} = 40 μ A, the power consumption Pc can be calculated as follows:

$$P_{C} = (V_{CC} - V_{O}) \times I_{O} + V_{CC} \times I_{CC}$$

= (13.5 V - 5.0 V) × 50 mA + 13.5 V × 40 μ A
= 0.43 W

At the ambient temperature Tamax = 125°C, the thermal Impedance (Junction to Ambient) θ_{JA} = 34 °C / W (4-layer PCB),

$$Tj = Tamax + P_C \times \theta_{JA}$$

= 125 °C + 0.43 W × 34 °C / W
= 139.6 °C

When operating the IC, the top center of case's (mold) temperature $T_T = 100$ °C, $\Psi_{JT} = 15$ °C / W (1-layer PCB),

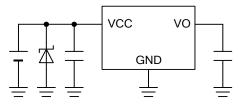
$$Tj = T_T + P_C \times \Psi_{JT} = 100 \ ^{\circ}C + 0.43 \ W \times 15 \ ^{\circ}C / W = 106.5 \ ^{\circ}C$$

For optimum thermal performance, it is recommended to expand the copper foil area of the board, increasing the layer and thermal via between thermal land pad.

Application Examples

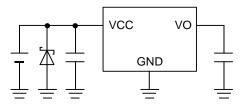
Applying positive surge to the VCC

If the possibility exists that surges higher than 45 V will be applied to the VCC, a Zener Diode should be placed between the VCC and GND as shown in the figure below.



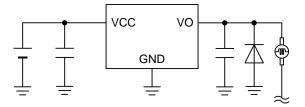
Applying negative surge to the VCC

If the possibility exists that negative surges lower than the GND are applied to the VCC, a Shottky Diode should be place between the VCC and GND as shown in the figure below.



Implementing a Protection Diode

If the possibility exists that a large inductive load is connected to the output pin resulting in back-EMF at time of startup and shutdown, a protection diode should be placed as shown in the figure below.



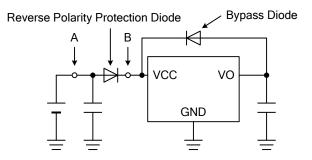
Reverse Polarity Protection Diode

In some applications, the VCC and pin potential might be reversed, possibly resulting in damage to internal circuit or damage to the element. In instance, when VCC shorts to GND while external capacitor at VO is charged.

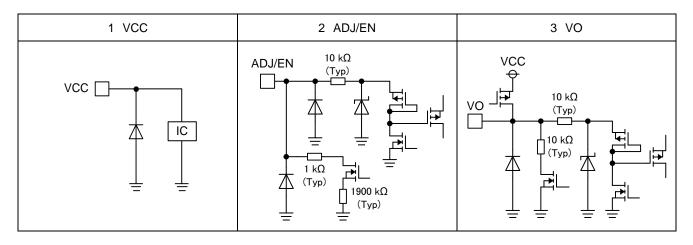
Reverse current in case of point A described in below diagram can be prevented by inserting Reverse polarity protection diode in series to the VCC.

When a short of the point B and the GND is concerned after having reverse polarity protection diode inserted, we recommend inserting a bypass diode between the VCC and the VO.

If the reverse polarity protection diode and bypass diode cannot be inserted due to any reasons, use a capacitor with a capacitance with less than 1000μ F at $V_{ADJ/EN} = 5V$ and 100μ F at $V_{ADJ/EN} = 16V$ to avoid damage to the internal circuits or the elements.



I/O equivalence circuits



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Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the maximum junction temperature rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

9. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

10. Unused Input Terminals

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

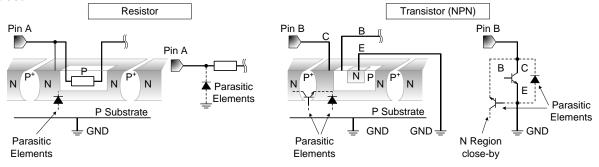
Operational Notes – continued

11. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.



12. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

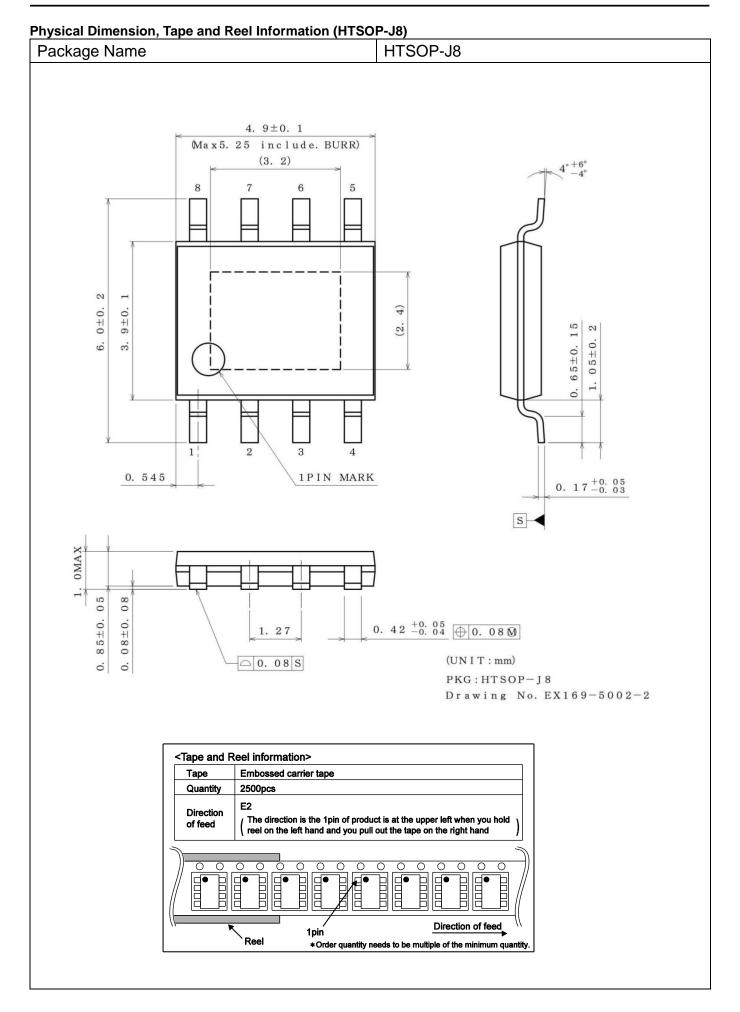
13. Thermal Shutdown Circuit(TSD)

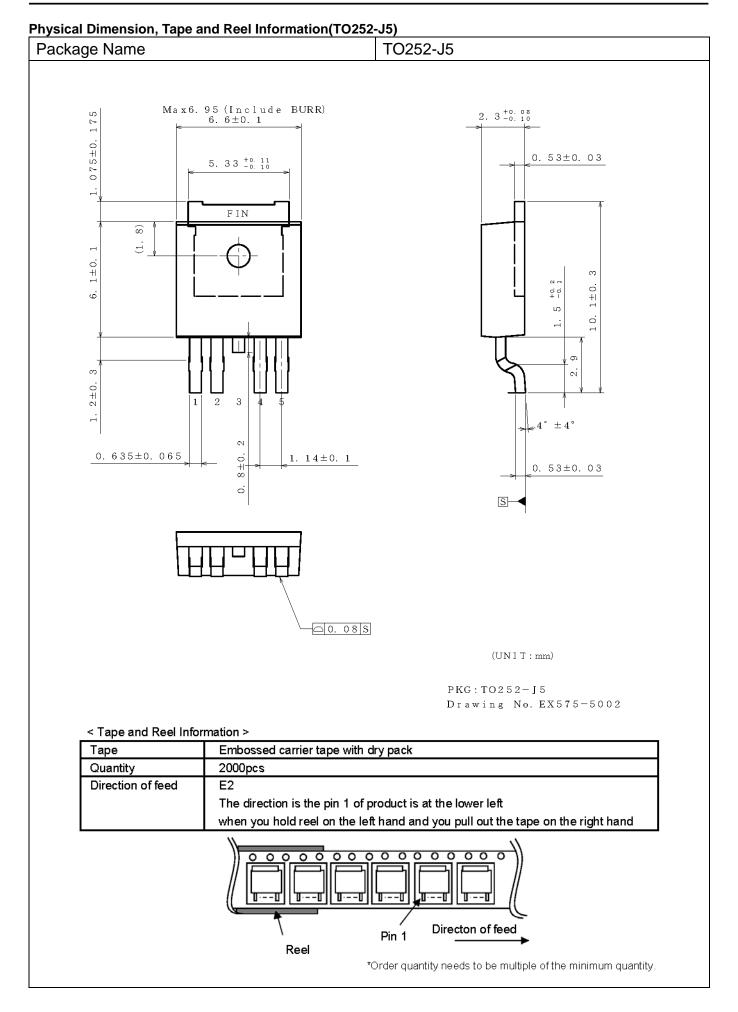
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

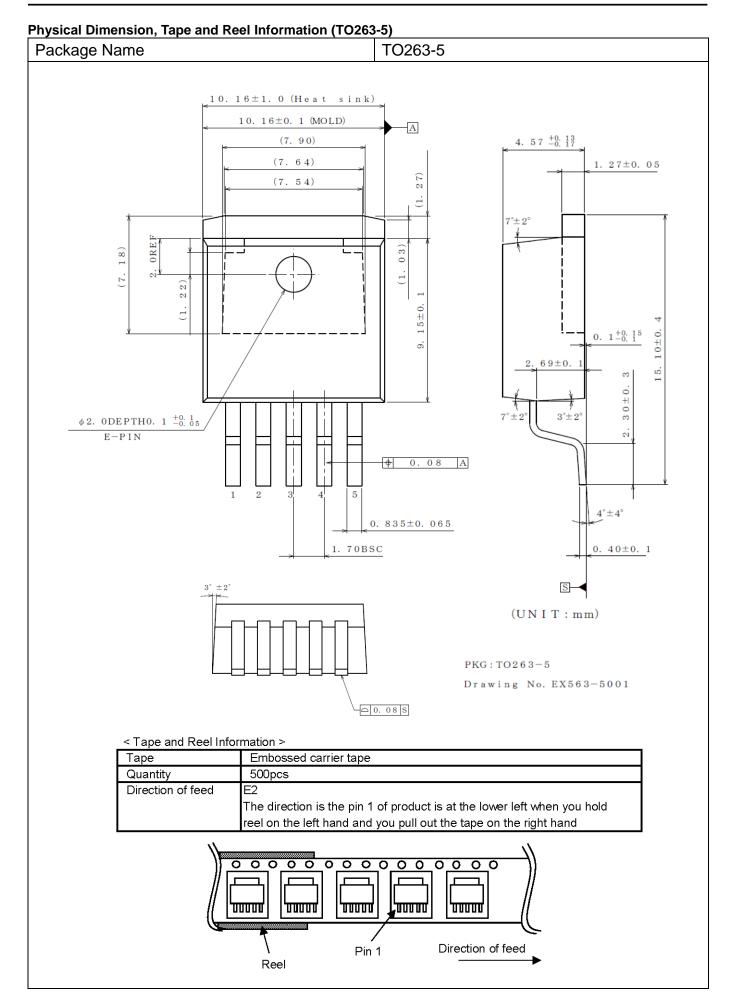
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

14. Over Current Protection Circuit (OCP)

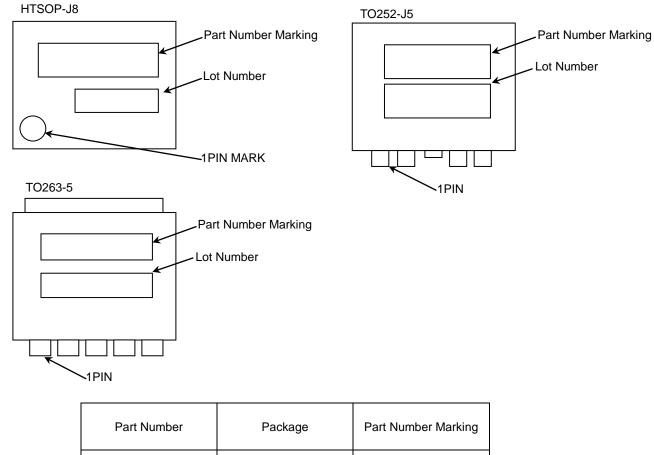
This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.







Marking Diagrams (Top View)



| Part Number | Package | Part Number Marking | |
|--------------|----------|---------------------|--|
| BD42530EFJ-C | HTSOP-J8 | 42530 | |
| BD42530FPJ-C | TO252-J5 | BD42530 | |
| BD42530FP2-C | TO263-5 | BD42530 | |

Revision History

| Date | Revision | Changes |
|-------------|----------|--|
| 20.Apr.2016 | 001 | New Release |
| 1.Dec.2016 | 002 | Page 1, 6 and 14, change value of minimum output capacitor and maximum ESR Page 1, 6 and 14, add comment of [recommended ceramic capacitor for output pin] Page 7, change format for Thermal Resistance |
| 29.Dec.2016 | 003 | Add TO252-J5 Package |

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| JAPAN | USA | EU | CHINA | |
|--------|--------|------------|---------|--|
| CLASSI | CLASSⅢ | CLASS II b | CLASSII | |
| CLASSⅣ | CLASSI | CLASSⅢ | CLASSII | |

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:

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[b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

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 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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